



N-Channel Reduced Q_q, Fast Switching MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	I _D (A)				
30	$0.0085 \text{ at V}_{GS} = 10 \text{ V}$	18			
	0.0125 at V _{GS} = 4.5 V	14			

PowerPAK SO-8

Bottom View

Ordering Information: Si7384DP-T1-E3 (Lead (Pb)-free)

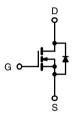
Si7384DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- · Halogen-free available
- TrenchFET® Gen II Power MOSFET
- PWM Optimized for High Efficiency
- New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile
- 100 % R_a Tested

APPLICATIONS

- High-Side DC/DC Conversion
 - Notebook
 - Desktop
 - Server



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	ss otherwise n	oted		
Parameter	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	30		V
Gate-Source Voltage		V_{GS}		V	
Continuous Drain Current (T _{.I} = 150 °C) ^a	T _A = 25 °C	I _D	18	11	
Continuous Dialii Curient (1 j = 150 °C)	T _A = 70 °C		14	8	
Pulsed Drain Current		I _{DM}	± 50		Α
Continuous Source Current (Diode Conduction) ^a		I _S	4.1	1.5	
Avalanche Current L = 0.1 mH		I _{AS}	25		
Single Pulse Avalanche Energy	gy L = 0.1 mH		32		mJ
Manianum Barray Disainational	T _A = 25 °C	- P _D	5	1.8	W
Maximum Power Dissipation ^a	T _A = 70 °C		3.2 1.1		VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature)b, c		, and the second	260		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manifesture Installation to Architect (MACCEFT)	t ≤ 10 s	R _{thJA}	21	25		
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State	' 'thJA	56	70	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	2.4	3.0		

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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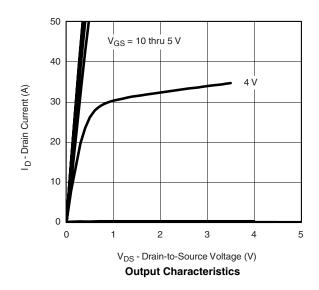
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	•		•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		3.0	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zara Cata Valta na Duain Comunit		V _{DS} = 30 V, V _{GS} = 0 V		1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			15	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α
		V _{GS} = 10 V, I _D = 18 A	0.007 0.0085		0.0085	0
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 14 \text{ A}$		0.0105	0.0125	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 18 A		56		S
Diode Forward Voltage ^a	V_{SD}	I _S = 4.1 A, V _{GS} = 0 V		0.78	1.1	٧
Dynamic ^b			•	1		
Total Gate Charge	Q_g			12	18	
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 18 \text{ A}$		5.9		nC
Gate-Drain Charge	Q _{gd}			4.0		
Gate Resistance	R_{g}		0.8	1.7	2.5	Ω
Turn-On Delay Time	t _{d(on)}			10	15	
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		13	20	1
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_G = 6 Ω		45	70	ns
Fall Time	t _f			13	20	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.8 A, di/dt = 100 A/μs		25	50	

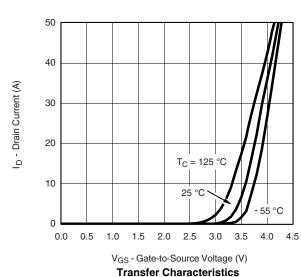
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





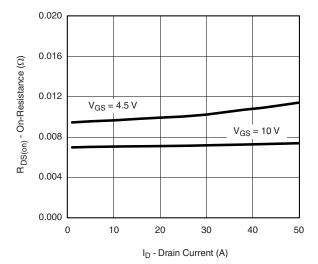
S-80439-Rev. C, 03-Mar-08



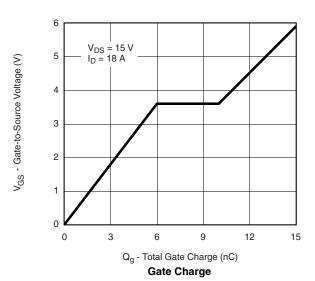




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



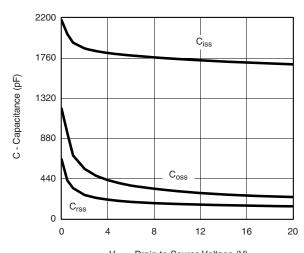
On-Resistance vs. Drain Current



T_J = 150 °C $T_{J} = 150 °C$ T_J = 25 °C

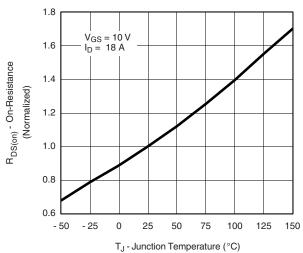
V_{SD}- Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

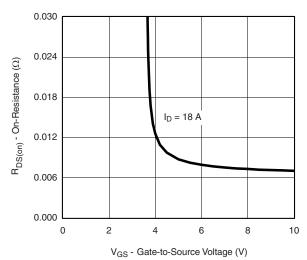


 V_{DS} - Drain-to-Source Voltage (V)





On-Resistance vs. Junction Temperature



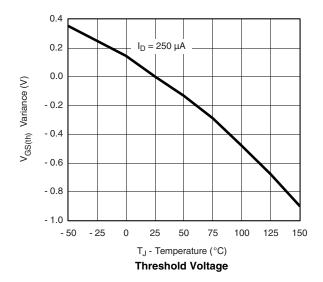
On-Resistance vs. Gate-to-Source Voltage

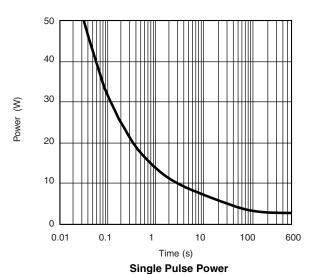
Is - Source Current (A)

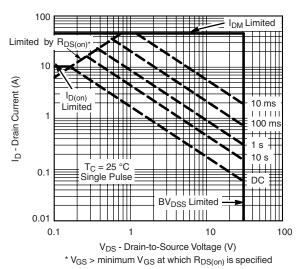
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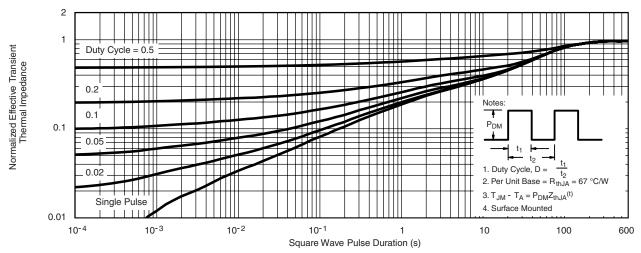
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



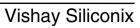




Safe Operating Area

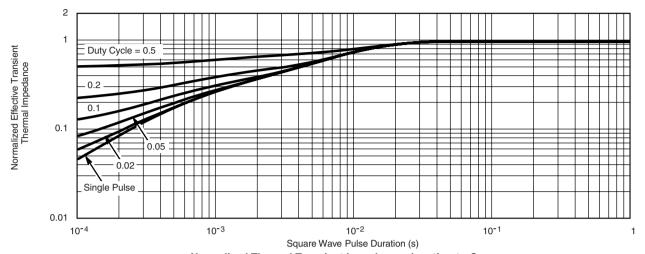


Normalized Thermal Transient Impedance, Junction-to-Ambient





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

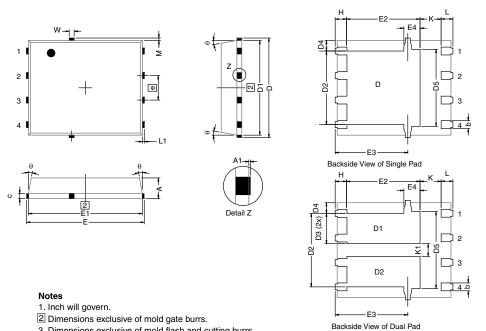
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72656.

Document Number: 72656 S-80439-Rev. C, 03-Mar-08



DWG: 5881

PowerPAK® SO-8, (Single/Dual)



	3. Dimensions exclusive of mold flash and cutting burrs.							
		MILLIMETERS		INCHES				
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
A	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
	4.00	4.00	F 00	0.400	0.400	0.407		

Α	0.97	1.04	1.12	0.038	0.041	0.044	
A1		-	0.05	0	-	0.002	
b	0.33	0.41	0.51	0.013	0.016	0.020	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	5.05	5.15	5.26	0.199	0.203	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.56	3.76	3.91	0.140	0.148	0.154	
D3	1.32	1.50	1.68	0.052	0.059	0.066	
D4		0.57 typ.			0.0225 typ.		
D5		3.98 typ.			0.157 typ.		
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	5.79	5.89	5.99	0.228	0.232	0.236	
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144	
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151	
E3	3.68	3.78	3.91	0.145	0.149	0.154	
E4 (for AL product)		0.58 typ. 0.023 typ					
E4 (for other product)		0.75 typ.		0.030 typ.			
е		1.27 BSC		0.050 BSC			
K (for AL product)		1.45 typ.		0.057 typ.			
K (for other product)		1.27 typ.			0.050 typ.		
K1	0.56	-	=	0.022	-	=	
Н	0.51	0.61	0.71	0.020	0.024	0.028	
L	0.51	0.61	0.71	0.020	0.024	0.028	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
M	0.125 typ.			0.005 typ.			
ECN: C13-0702-Rev. K, 20)-May-13			•			

Revison: 20-May-13 Document Number: 71655



RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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Revision: 02-Oct-12 Document Number: 91000